Seat No.: _____

Enrolment No._____

GUJARAT TECHNOLOGICAL UNIVERSITY BE - SEMESTER-V EXAMINATION – WINTER 2015

Subject Code: 151703Date:05/12/2Subject Name: Electronics in Industries			15	
	ne: 1 cructio	10:30am to 1:00pm Total Marks: 70		
	1. 2. 3.	Attempt all questions. Make suitable assumptions wherever necessary.		
Q.1	(a) (b)	Explain the constructional details, working and characteristics of an SCR. Describe half wave controlled rectifier with inductive load and flywheel diode.	07 07	
Q.2	(a)	What do you mean by commutation? Discuss any two methods of commutation of thyristor.	07	
	(b)	Explain uni-junction transistor, its biasing and application. OR	07	
	(b)	Explain the operation of a two-thyristor center-tapped controlled rectifier and draw its input and output waveforms.	07	
Q.3	(a)	With neat sketch explain structure, symbol and V-I characteristics of Silicon Controlled Switch.	07	
	(b)	Explain three phase center-tapped full wave uncontrolled rectifier. OR	07	
Q.3	(a)	Describe Shockley diode with neat sketch of its V-I characteristic, sectional view and symbol.	07	
	(b)	Enlist various turn on methods of thyristor. Explain dV/dt turn on in detail.	07	
Q.4	(a)	Classify single-phase controlled rectifier and compare half-wave and full-wave controlled rectifier.	07	
	(b)	Explain the working principle of Dual converter. OR	07	
Q.4	(a) (b)	Prepare PUT Firing Circuit and list-out its advantages and disadvantages. Explain the switching characteristics of an IGBT.	07 07	
Q.5	(a) (b)	Write about Diode-Resistance-Capacitance firing circuit. Write a note on transistor analogue of a thyristor. OR	07 07	
Q.5	(a) (b)	Explain the effect of free-wheeling diode in detail. Describe six phase full wave controlled bridge rectifier.	07 07	
